

Lecture Notes - 3

Resistance & Capacitance

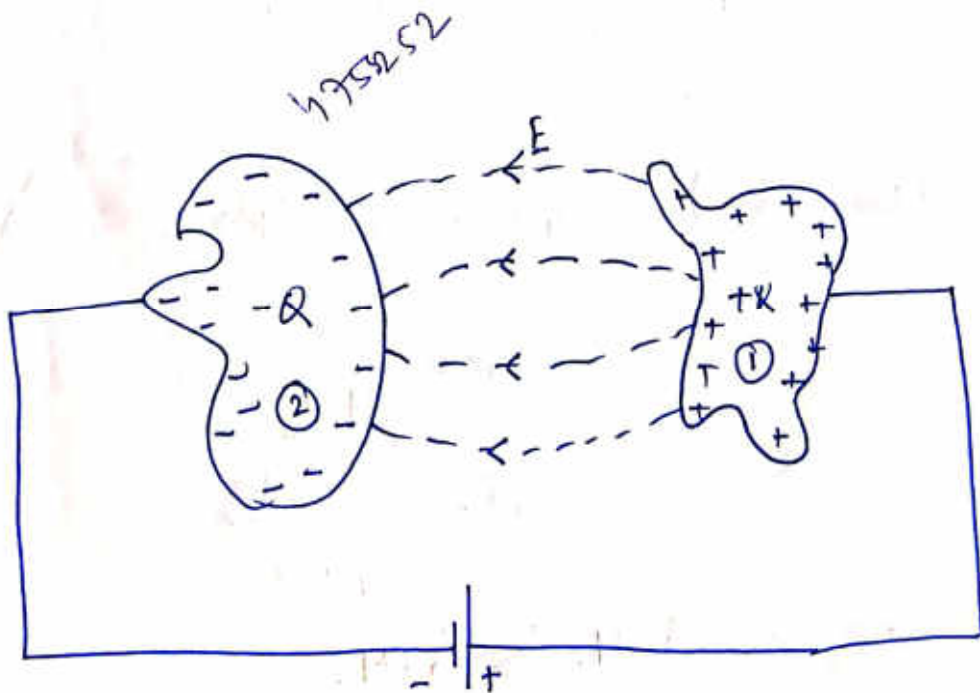
$$R = \frac{\rho_c l}{S}$$

$$R = \frac{V}{I} = \frac{\int \vec{E} \cdot d\vec{l}}{\int \sigma \vec{E} \cdot d\vec{s}}$$

$$P = I^2 R$$

the resistance R (or conductance $G = \frac{1}{R}$) of a given conducting material can be found by following steps:

1. Choose a suitable coord system
2. Assume V_0 as the pot diff betⁿ the an^d terminal
3. Solve Laplace's eqⁿ $\nabla^2 V = 0$ to obtain V then determine \vec{E} from $\vec{E} = -\nabla V$ and find I from $I = \int \sigma \vec{E} \cdot d\vec{s}$
4. Finally, obtain R as V_0/I .

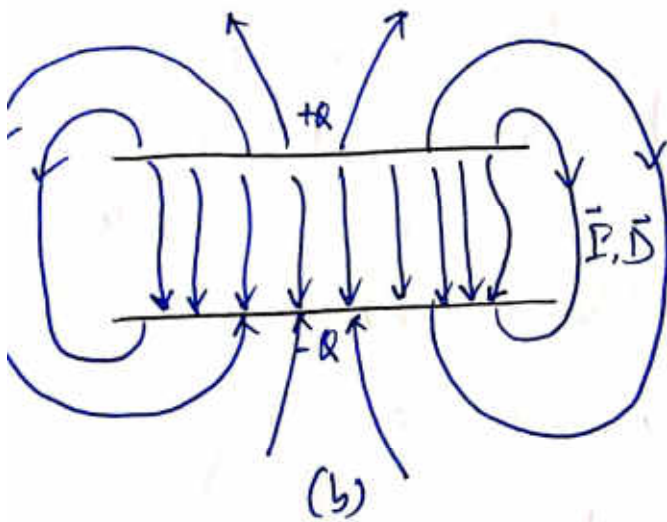
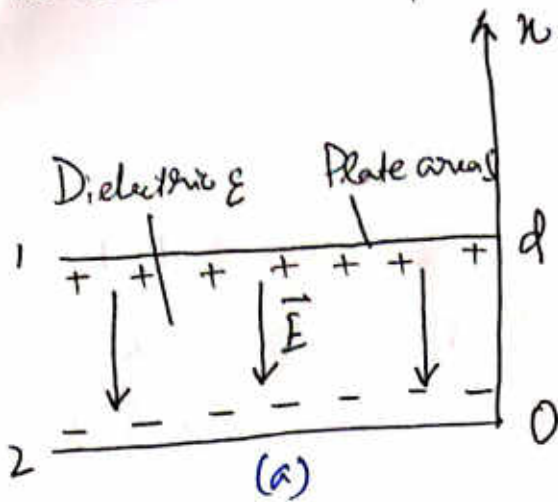


$$V = V_1 - V_2 = - \int_2^1 \vec{E} \cdot d\vec{l}$$

$$C = \frac{Q}{V} = \frac{\epsilon_0 \oint \vec{E} \cdot d\vec{s}}{\int \vec{E} \cdot d\vec{l}}$$

①

Parallel-Plate Capacitor



$$P_s = \frac{Q}{S} \quad \vec{D} = -P_s \hat{a}_n$$

$$\vec{E} = \frac{P_s}{\epsilon} (-\hat{a}_n)$$

$$V = - \int_1^2 \vec{E} \cdot d\vec{l} = - \int_0^d \left[-\frac{Q}{\epsilon S} \hat{a}_n \right] dx \hat{a}_n$$

$$= \frac{Qd}{\epsilon S}$$

and thus for a parallel-plate capacitor

$$C = \frac{Q}{V} = \frac{\epsilon S}{d}$$

energy stored $E_r = \frac{C}{C_0}$

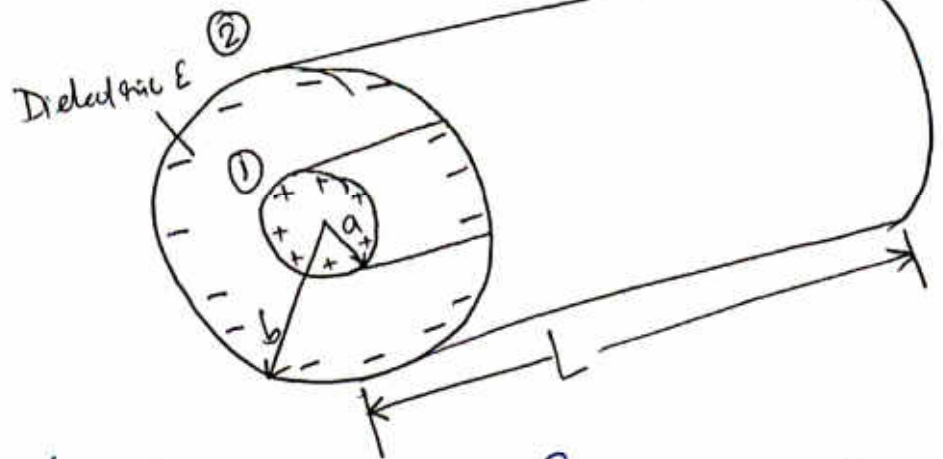
$$W_E = \frac{1}{2} C V^2 = \frac{1}{2} Q V = \frac{Q^2}{2C}$$

$$W_E = \frac{1}{2} \int_V \vec{D} \cdot \vec{E} dV = \frac{1}{2} \int_V \epsilon E^2 dV$$

$$* W_E = \frac{1}{2} \int_V \epsilon \frac{Q^2}{\epsilon^2 S^2} dV = \frac{\epsilon Q^2 S d}{2 \epsilon^2 S^2}$$

$$= \frac{Q^2}{2} \left(\frac{d}{\epsilon S} \right) = \frac{Q^2}{2C} = \frac{1}{2} Q V$$

Coaxial Capacitor



By applying Gauss's law to an arb. Gaussian cylindrical surface p ($a < p < b$) we obtain

$$Q = \oint \vec{E} \cdot d\vec{s} = \epsilon E_p 2\pi p L$$

Hence:

$$E = \frac{Q}{2\pi \epsilon p L} \hat{a}_p$$

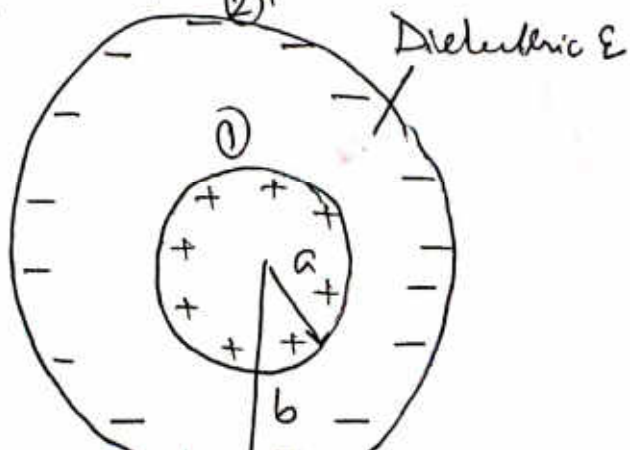
$$V = - \int_1^2 \vec{E} \cdot d\vec{l} = - \int_a^b \left[\frac{Q}{2\pi \epsilon p L} \hat{a}_p \right] \cdot dp \hat{a}_p$$

$$= \frac{Q}{2\pi \epsilon L} \ln \frac{b}{a}$$

Thus the capacitance of a coaxial cylinder is given by

$$C = \frac{Q}{V} = \frac{2\pi \epsilon L}{\ln \frac{b}{a}}$$

Spherical Capacitor



Gaussian spherical surface of radius r ($a < r < b$)

$$Q = \oint \vec{E} \cdot d\vec{s} = \epsilon E_r 4\pi r^2$$

$$\vec{E} = \frac{Q}{4\pi \epsilon r^2} \hat{a}_r$$

$$V = - \int_a^b \vec{E} \cdot d\vec{l} = - \int_a^b \left[\frac{Q}{4\pi\epsilon r^2} \hat{a}_r \right] \cdot dr \hat{a}_r$$

$$= \frac{Q}{4\pi\epsilon} \left[\frac{1}{a} - \frac{1}{b} \right]$$

Thus the capacitance of the spherical capacitor is

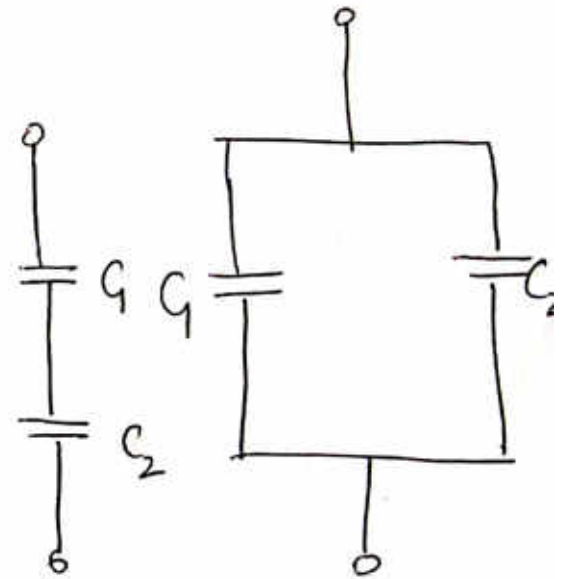
$$C = \frac{Q}{V} = \frac{4\pi\epsilon}{\frac{1}{a} - \frac{1}{b}}$$

by letting $b \rightarrow \infty$, $C = 4\pi\epsilon a$

$$R = \frac{V}{I} = \frac{\int \vec{E} \cdot d\vec{l}}{\oint \vec{\sigma E} \cdot d\vec{s}}$$

$$C = \frac{Q}{V} = \frac{\epsilon \oint \vec{E} \cdot d\vec{s}}{\int \vec{E} \cdot d\vec{l}}$$

$$RC = \frac{\epsilon}{\sigma}$$



$$\frac{1}{C} = \frac{1}{C_1} + \frac{1}{C_2}$$

$$C = C_1 + C_2$$

which is the relaxation time T_r of $C = \frac{C_1 C_2}{C_1 + C_2}$ the medium separating the conductors.

parallel plate capacitor

$$C = \frac{\epsilon S}{d}, \quad R = \frac{d}{\sigma S}$$

Isolated Sph. conduct

$$C = 4\pi\epsilon a$$

$$R = \frac{1}{4\pi\sigma a}$$

Cylindrical capacitor

$$C = \frac{2\pi\epsilon L}{\ln \frac{b}{a}}, \quad R = \frac{\ln \frac{b}{a}}{2\pi\sigma L}$$

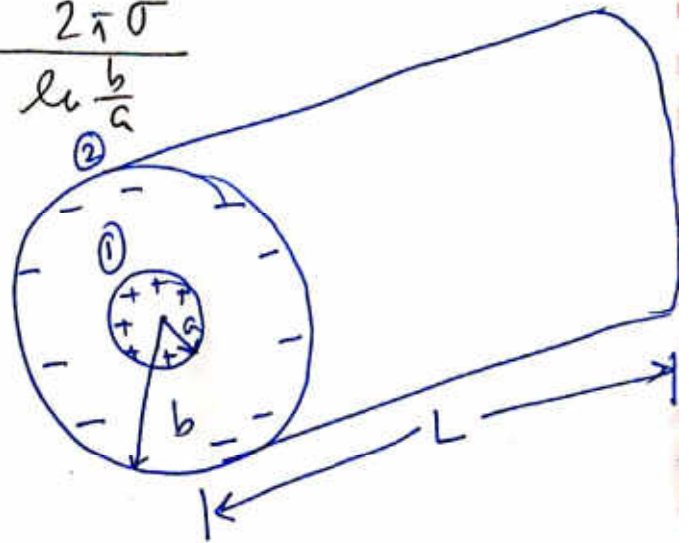
Sph. Capacitor

$$C = \frac{4\pi\epsilon}{\frac{1}{a} - \frac{1}{b}}, \quad R = \frac{\frac{1}{a} - \frac{1}{b}}{4\pi\sigma}$$

Ex. A Coaxial cable contains an insulating material of conductivity σ . If the radius of the central wire is a and that of the sheath is b , show that the conductance of the cable per unit length is $G = \frac{2\pi\sigma}{\ln \frac{b}{a}}$

Solⁿ: Let V_0 be the pot. diffⁿ betⁿ the inner & outer end^s

$$V(r=a) = 0 \text{ and } V(r=b) = V_0$$



$$\vec{J} = \sigma \vec{E} = \frac{-\sigma V_0}{\rho \ln \frac{b}{a}} \hat{a}_\rho$$

$$d\vec{s} = -\rho d\phi dz \hat{a}_\rho$$

$$I = \int \vec{J} \cdot d\vec{s} = \int_{\phi=0}^{2\pi} \int_{z=0}^L \frac{V_0 \sigma}{\rho \ln \frac{b}{a}} \rho dz d\phi$$

$$= \frac{2\pi L \sigma V_0}{\ln \frac{b}{a}}$$

The resistance per unit length is

$$R = \frac{V_0}{I} \cdot \frac{1}{L} = \frac{\ln \frac{b}{a}}{2\pi\sigma}$$

and the conductance per unit length is

$$G = \frac{1}{R} = \frac{2\pi\sigma}{\ln \frac{b}{a}} \text{ as required.}$$